Supporting information

Solution-Grown Millimeter-Scale Mn-Doped CsPbBr₃/Cs₄PbBr₆ Crystals with Enhanced Photoluminescence and Stability for Light-Emitting Application

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Fig. S1 (a) Photograph of CsPbBr₃/Cs₄PbBr₆ crystals under UV light. ($\lambda_{ex} = 395$ nm) (b) Photograph of pure Cs₄PbBr₆ single crystals under UV light ($\lambda_{ex} = 395$ nm). (c) The screw micrometer is zeroed, and the zero error is determined to be -0.007 mm. (d) Thickness measurement picture of CsPbBr₃/Cs₄PbBr₆ crystal. (e) Thickness measurement picture of Cs₄PbBr₆ single crystal.



Just prepared After 1 year

Fig. S2 Photographs of CsPbBr₃/Cs₄PbBr₆ crystals ground into powder under UV light ($\lambda _{ex} = 395 \text{ nm}$).



Fig. S3 (a) Typical TEM image of a particle processed from as-grown CsPbBr₃/Cs₄PbBr₆ crystals (b) The corresponding enlarged TEM image of panel a plotted with lattice spacing. (c) HRTEM image of the same particle with panel a processed from CsPbBr₃/Cs₄PbBr₆ crystals. The inset is the corresponding FFT pattern. (d) Another HRTEM image of the same particle with panel a processed from CsPbBr₃/Cs₄PbBr₆ crystals, and the inset is the corresponding FFT pattern.



Fig. S4 PLQY image of just prepared CsPbBr₃/Cs₄PbBr₆ crystals.



Fig. S5 PLQY image of just prepared Mn-doped CsPbBr₃/Cs₄PbBr₆ crystals.



Fig. S6 PLQY image of CsPbBr₃/Cs₄PbBr₆ crystals directly placed under an air atmosphere after three months.



Fig. S7 PLQY image of Mn-doped CsPbBr₃/Cs₄PbBr₆ crystals stored directly placed under an air atmosphere for three months.



Fig. S8 The EDS spectra of Mn-doped CsPbBr₃/Cs₄PbBr₆ crystals.



Fig. S9 (a) The temperature-dependent PL spectra of $CsPbBr_3/Cs_4PbBr_6$ crystals. (b) The temperature-dependent PL spectra of Mn^{2+} doped $CsPbBr_3/Cs_4PbBr_6$ crystals.



Fig. S10 (a) PL spectra of CsPbBr₃/Cs₄PbBr₆ crystals under a humid condition with humidity of 70%. (b) PL spectra of Mn^{2+} doped CsPbBr₃/Cs₄PbBr₆ crystals under a humid condition with humidity of 70%.



Fig. S11 (a) The PL spectra of CsPbBr₃/Cs₄PbBr₆ crystals under 455 nm laser irradiation with a power density of 5 W/cm². (b) The PL spectra of Mn^{2+} doped CsPbBr₃/Cs₄PbBr₆ crystals under 455 nm laser irradiation with a power density of 5 W/cm².



Fig. S12 Normalized PL spectra of Mn-doped and undoped CsPbBr₃/Cs₄PbBr₆ crystals with different content of Mn²⁺ ions. x is expressed as the amount of substance of MnBr₂ in the CsPbBr₃/Cs₄PbBr₆ crystal doped with Mn²⁺ ions, x = 0.4 mmol and x = 1 mmol, respectively.

Table S1 Summary of the EDS analysis of Mn-doped CsPbBr₃/Cs₄PbBr₆ crystals.

Element	Wt%	Wt%
		Sigma
Mn	0.27	0.40
Br	35.00	5.90
Cs	41.19	9.64
Pb	23.54	4.22